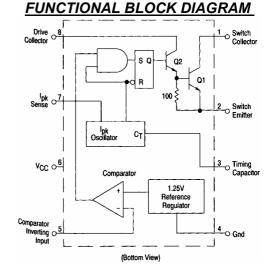
DC-TO-DC CONVERTER CONTROL CIRCUITS

The IL34063Ais a monolithic control circuit containing the primary functions required for DC-to-DC converters. These devices consist of an internal temperature compensated reference, comparator, controlled duty cycle oscillator with an active current limit circuit, driver and high current output switch. This series was specifically designed to be incorporated in Step-Down and Step-Up and Voltage-Inverting applications with a minimum number of external components.

FEATURES

- Operation from 3.0 V to 40 V Input
- Low Standby Current
- Current Limiting
- Output Switch Current to 1.5 A
- Output Voltage Adjustable
- Frequency Operation to 100 kHz
- Precision 2% Reference



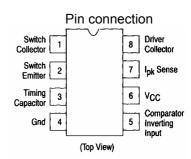
MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Power Supply Voltage	V _{CC}	40	Vdc
Comparator Input Voltage Range	V_{IR}	-0.3 to +40	Vdc
Switch Collector Voltage	$V_{C(switch)}$	40	Vdc
Switch Emitter Voltage (Vpin 1 = 40 V)	$V_{E(switch)}$	40	Vdc
Switch Collector to Emitter Voltage	V _{CE(switch)}	40	Vdc
Driver Collector Voltage	I _{C(driver)}	40	Vdc
Driver Collector Current (Note 1)	I _{C(driver)}	100	mA
Switch Current	I _{SW}	1.5	Α
Power Dissipation and Thermal Characteristics			
Ceramic Package, U Suffix T _A = +25°C	P_{D}	1.25	W
Thermal Resistance	$R_{ hetaJA}$	100	°C/W
Plastic Package, P Suffix T _A = +25°C	P_{D}	1.25	W
Thermal Resistance	$R_{ heta JA}$	100	°C/W
SOIC Package, D Suffix TA = +25°C	P_{D}	625	mW
Thermal Resistance	$R_{ hetaJA}^{-}$	160	°C/W
Operating Junction Temperature	TJ	+150	°C
Operating Ambient Temperature Range	T _A	0 to +70	°C
Storage Temperature Range	Tstg	-65to+150	°C



ORDERING INFORMATION

Device	Temperature	Package	
	Range		
	0° to +70°C	SO-8	
IL34063A			
D			
IL34063A		Plastic DIP	
P1			



<u>ELECTRICAL CHARACTERICISTICS</u> ($V_{CC} = 5.0 \text{ V}$, $T_A = 0 \text{ to } +70^{\circ}\text{C}$ unless otherwise specified.)

Characteristics	Symbol	Min	Тур	Max	Unit				
OSCILLATOR									
Frequency ($V_{Pin 5} = 0 \text{ V}, C_{T} = 1.0 \text{ nF}, T_{A} = 25^{\circ}\text{C}$)	fosc	24	33	42	kHz				
Charge Current ($V_{CC} = 5.0 \text{ V}$ to 40 V, $T_A = 25^{\circ}\text{C}$)	Ichg	24	33	42	μΑ				
Discharge Current ($V_{CC} = 5.0 \text{ V to } 40 \text{ V}, T_A = 25^{\circ}\text{C}$)	Idischg	140	200	260	μΑ				
Discharge to Charge Current Ratio (Pin7 to Vcc, T _A =25°C)	Idischg/Ichg	5.2	6.2	7.5					
Current Limit Sense Voltage (Ichg = Idischg, T _A = 25°C)	Vlpk(sense)	250	300	350	mV				
OUTPUT SWITCH (Note 3)									
Saturation Voltage, Darlington Connection (I_{SW} = 1.0 A, Pins 1, 8 connected)	V _{CE} (sat)	_	1.0	1.3	V				
Saturation Voltage (I_{SW} = 1.0 A, $R_{Pin 8}$ = 82 Ω to V_{CC} .	V _{CE} (sat)	_	0.45	0.7	V				
Forced β = 20)									
DC Current Gain ($I_{SW} = 1.0 \text{ A}, V_{CE} = 5.0 \text{ V}, T_A = 25^{\circ}\text{C}$)	h _{FE}	50	120	_	_				
Collector Off-State Current (V _{CE} = 40V)	I _C (off)	_	0.01	100	μΑ				
COMPARATOR									
Threshold Voltage (T _A = 25°C)	Vth	1.225	1.25	1.275	V				
$(T_A = T_{LOW} \text{ to } T_{HIGH})$		1.21		1.29					
Threshold Voltage Line Regulation (V _{CC} = 3 0 V to 40 V)	Regime		1.4	5.0	mV				
Input Bias Current (Vin=0V)	I _{IB}	_	-40	-400	nA				
TOTAL DEVICE									
Supply Current (V_{CC} = 5 0 V to 40 V, C_T = 1 0 nF, V_{pin7} = V_{CC} . V_{Pin5} > Vth, Pin 2 = Gnd, Remaining pins open)	I _{CC}		2.5	4.0	mA				

NOTES:

- 1. Maximum package power dissipation limits must be observed.
- Low duty cycle pulse techniques are used during test to maintain Junction temperature as close to ambient 2. temperature as possible
- If the output switch is driven into hard saturation (non Darlington configuration) at low switch currents (< 300 mA) and 3. currents (>30 mA), it may take up to 2.0 µs to come out of saturation This condition will shorten the off time at frequencies > 30 kHz, and is magnified at high temperatures This condition does not occur with a Darlington configuration, since the output switch cannot saturate If a non Darlington configuration is used, the following output drive condition is recommended

Forced β of output switch = I_C, output/(Ic, driver -7.0 mA*) > 10

*The 100 Ω. resistor in the emitter of the driver device requires about 7.0 mA before the output switch conducts



PAD LOCATION

